# NSN 5961-00-999-7088

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Inclosure Material:

Metal

**Overall Length:** 

0.547 inches

# **Overall Diameter:**

1.281 inches

**Mounting Facility Quantity:** 

1

# Internal Configuration:

Junction contact

## **Mounting Method:**

Threaded stud

## Features Provided:

Hermetically sealed case

## **Thread Size:**

0.190 inches

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

85.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 25.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current

# Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# Thread Series Designator:

Unf

# **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

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